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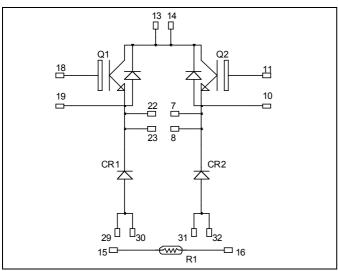




Dual Buck chopper NPT IGBT Power Module

$$V_{CES} = 600V$$

 $I_{C} = 50A$ @ $Tc = 80$ °C



16 29 30 15 31 14 32 13 10

All multiple inputs and outputs must be shorted together Example: 13/14; 29/30; 22/23 ...

Application

- AC and DC motor control
- Switched Mode Power Supplies

Features

- Non Punch Through (NPT) Fast IGBT
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 50 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
 - Symmetrical design
- Kelvin emitter for easy drive
- Very low stray inductance
- High level of integration
- Internal thermistor for temperature monitoring

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- Easy paralleling due to positive TC of VCEsat
- Each leg can be easily paralleled to achieve a single buck of twice the current capability.
- RoHS compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		600	V
$I_{\rm C}$	Continuous Collector Current	$T_C = 25$ °C	65	
1 _C	Continuous Conector Current	$T_C = 80^{\circ}C$	50	Α
I_{CM}	Pulsed Collector Current	$T_C = 25$ °C	230	
V_{GE}	Gate – Emitter Voltage		±20	V
P_D	Maximum Power Dissipation	$T_C = 25$ °C	250	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125$ °C	100A@500V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

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All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
T	Zero Gate Voltage Collector Current	$V_{GE} = 0V$	$T_j = 25^{\circ}C$			250	иA
I_{CES}	Zero Gate Voltage Concetor Current	$V_{CE} = 600V$	$T_j = 125$ °C			500	μΛ
V _{CE(sat)}	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C	1.7	2.0	2.45	V
V CE(sat)	Conector Emitter Saturation Voltage	$I_C = 50A$	$T_j = 125$ °C		2.2		v
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C =$	1mA	4		6	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

Dynamic Characteristics

•	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$			2200		
C_{oes}	Output Capacitance	$V_{CE} = 25V$			323		pF
C_{res}	Reverse Transfer Capacitance	f = 1MHz			200		
Q_{g}	Total gate Charge	$V_{GE} = 15V$			166		
Q_{ge}	Gate – Emitter Charge	$V_{Bus} = 300V$			20		nC
Q_{gc}	Gate – Collector Charge	$I_C = 50A$			100		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switch	ning (25°C)		40		
T_{r}	Rise Time	$V_{GE} = 15V$			9		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 400V$ $I_{\text{C}} = 50A$			120		ns
$T_{\rm f}$	Fall Time	$R_G = 2.7\Omega$			12		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C)			42		
T_{r}	Rise Time	$V_{GE} = 15V$			10		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 400V$ $I_{\text{C}} = 50A$			130		ns
T_{f}	Fall Time	$R_G = 2.7\Omega$			21		
Eon	Turn-on Switching Energy	$V_{GE} = 15V$ $V_{Bus} = 400V$	$T_j = 125$ °C		0.5		I
$\mathrm{E}_{\mathrm{off}}$	Turn-off Switching Energy	$I_C = 50A$ $R_G = 2.7\Omega$	$T_j = 125$ °C		1		mJ

Chopper diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			600			V
I_{RM}	Maximum Reverse Leakage Current $V_R=600V$ T_j	$T_j = 25^{\circ}C$			250	^	
1 _{RM}	Waximum Reverse Leakage Current	$T_{j} = 12$	$T_j = 125$ °C			500	μΑ
I_F	DC Forward Current		$Tc = 70^{\circ}C$		60		A
	Diode Forward Voltage	$I_F = 60A$			1.6	1.8	
$V_{\rm F}$		$I_F = 120A$			1.9		V
		$I_F = 60A$ $T_j = 125^{\circ}$	$T_j = 125$ °C		1.4		
t_{rr}	Reverse Recovery Time $I_{rr} = 60 \text{ A}$	$I_F = 60A$	$T_j = 25$ °C		130		ns
rr				$T_{j} = 125^{\circ}C$		170	
0	Q_{rr} Reverse Recovery Charge $di/dt = 200 A/\mu s$	$T_j = 25$ °C		220		пC	
Q rr		· ,	$T_{i} = 125^{\circ}C$		920		iiC



 $Temperature\ sensor\ NTC\ (\text{see application note APT0406 on www.microsemi.com for more information}).$

Symbol	Characteristic	Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C		50		kΩ
B _{25/85}	$T_{25} = 298.15 \text{ K}$	·	3952		K

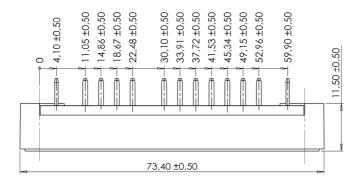
$$R_{T} = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{75}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$

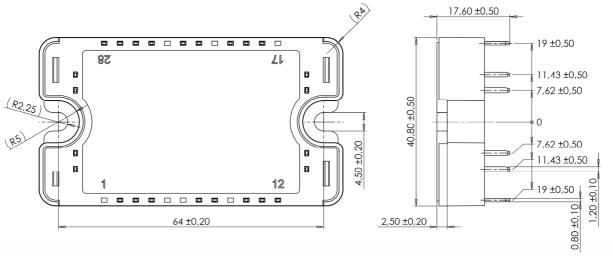
$$R_{T}: \text{ Thermistor value at T}$$

Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance		IGBT			0.5	°C/W
KthJC			Diode		0.9	C/ VV	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz		4000			V	
T_{J}	Operating junction temperature range Storage Temperature Range			-40		150	
T_{STG}			-40		125	°C	
$T_{\rm C}$	Operating Case Temperature		-40		100		
Torque	Mounting torque	To heatsink	M4	2		3	N.m
Wt	Package Weight		•			110	g

SP3 Package outline (dimensions in mm)

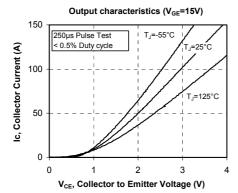


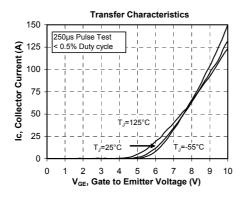


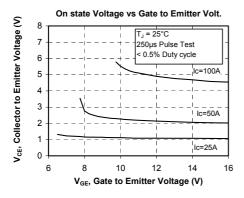
See application note 1901 - Mounting Instructions for SP3 Power Modules on www.microsemi.com

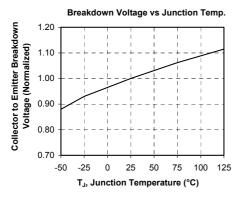


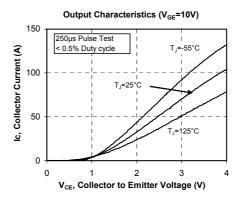
Typical Performance Curve

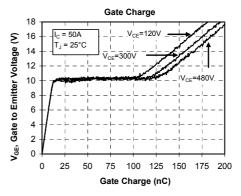


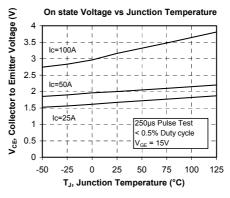


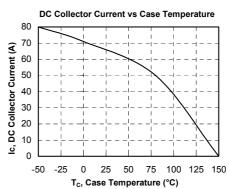




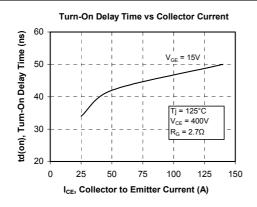


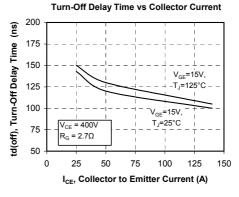


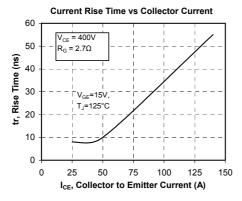


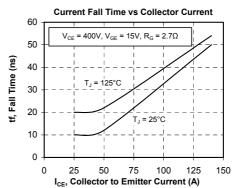


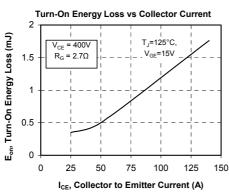


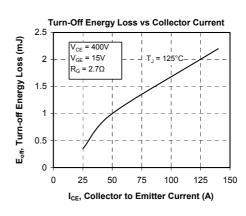


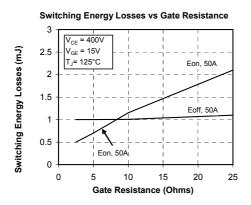


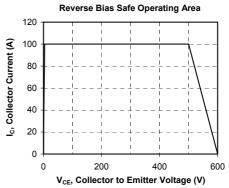




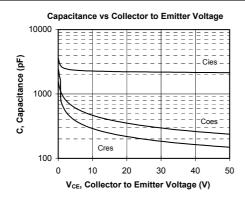


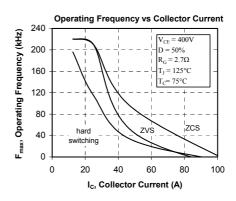


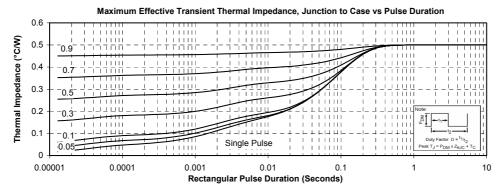














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